

## DIGITAL OUTPUT PHOTO REFLECTOR

### ■ GENERAL DESCRIPTION

The NJL5805K is a thin package photo reflectors designed for car-audio applications. Durability under the temperature cycle has been greatly improved by applying a newly developed resin, (Compared to our conventional products, the durability has been doubled.)

### ■ APPLICATIONS

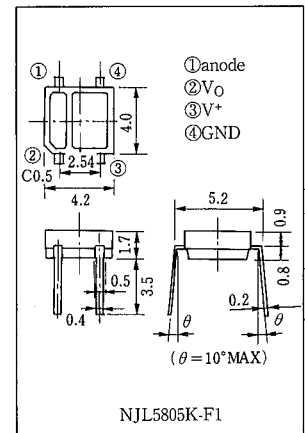
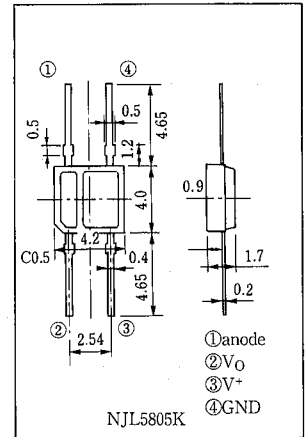
- The end detector for car-video or audio tape etc.
- Rotation detection and control to be applied for car audio turntable

### ■ ABSOLUTE MAXIMUM RATINGS (Ta=25°C)

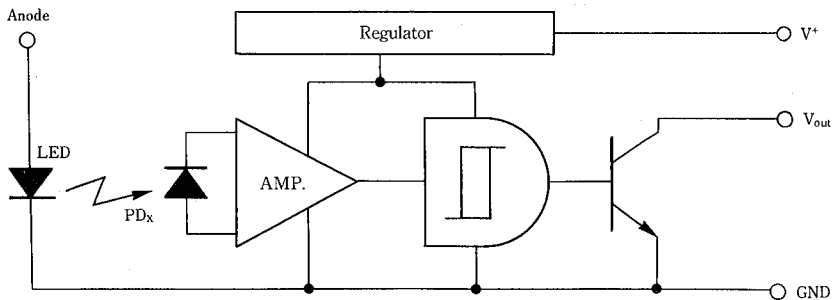
PARAMETER	SYMBOL	RATINGS	UNIT
<b>Emitter</b>			
Forward Current (Continuous)	I <sub>F</sub>	25	mA
Reverse Voltage (Continuous)	V <sub>R</sub>	6	V
Power Dissipation	P <sub>D</sub>	45	mW
<b>Detector</b>			
Supply Voltage	V <sup>+</sup>	16	V
High Level Output Voltage	V <sub>OH</sub>	16	V
Low Level Output Current	I <sub>OL</sub>	16	mA
Power Dissipation	P <sub>O</sub>	110	mW
<b>Coupler</b>			
Total Power Dissipation	P <sub>tot</sub>	130	mW
Operating Temperature	T <sub>opr</sub>	-20~+75	°C
Storage Temperature	T <sub>stg</sub>	-40~+85	°C
Soldering Temperature	T <sub>sol</sub>	260	°C

(Ssec. 1.5mm from body)

### ■ OUTLINE (typ.) Unit: mm



### ■ BLOCK DIAGRAM

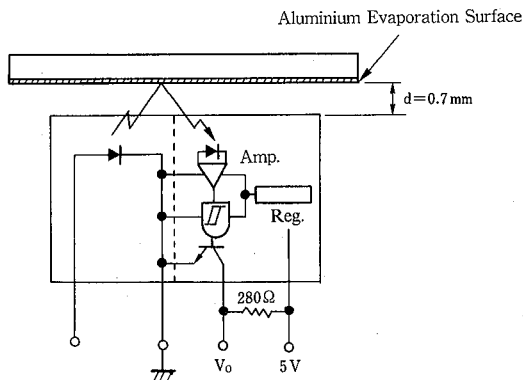


## ■ ELECTRO-OPTICAL CHARACTERISTICS (Ta=25°C)

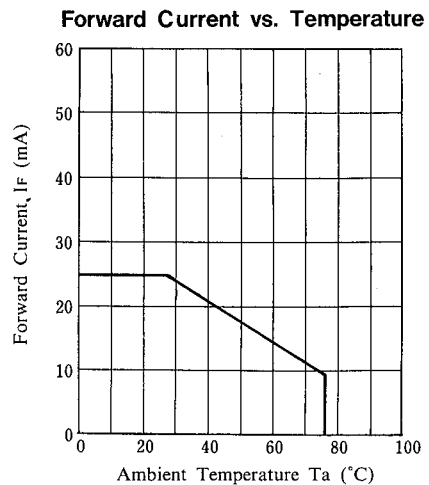
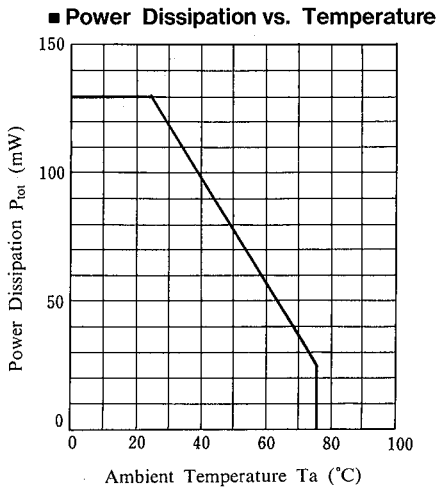
PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
<b>Emitter</b>						
Forward Voltage	$V_F$	$I_F = 10\text{mA}$	—	—	1.3	V
Reverse Current	$I_R$	$V_R = 6\text{V}$	—	—	10	$\mu\text{A}$
Capacitance	$C_t$	$V_R = 0\text{V}, f = 1\text{MHz}$	—	25	—	pF
<b>Detector</b>						
Supply Voltage Range	$V^+$		4.5	—	15	V
Low Level Output Voltage	$V_{OL}$	$I_{OL} = 16\text{mA}, V^+ = 5\text{V}, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	0.2	0.5	V
High Level Output Current	$I_{OH}$	$V_O = V^+ = 6\text{V}, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	—	100	$\mu\text{A}$
Low Level Supply Current	$I_{CCL}$	$V^+ = 5\text{V}, I_F = 0\text{mA}$	—	4.5	10	mA
High Level Supply Current	$I_{CCH}$	$V^+ = 5\text{V}, I_F = 10\text{mA}, d = 0.7\text{mm}$	—	3	10	mA
<b>Coupled</b>						
L-H Threshold Input Current	$I_{FLH}$	$V^+ = 5\text{V}, R_L = 280\Omega, d = 0.7\text{mm}$	—	5	10	mA
Hysteresis	$I_{FHL}/I_{FLH}$	$V^+ = 5\text{V}, R_L = 280\Omega, d = 0.7\text{mm}$	—	0.8	—	
L→H Delay Time	$t_{PLH}$	$V^+ = 5\text{V}, I_F = 10\text{mA}, R_L = 280\Omega, d = 0.7\text{mm}$	—	10	—	$\mu\text{s}$
H→L Delay Time	$t_{PHL}$	$V^+ = 5\text{V}, I_F = 10\text{mA}, R_L = 280\Omega, d = 0.7\text{mm}$	—	5	—	$\mu\text{s}$
Rise Time	$t_r$	$V^+ = 5\text{V}, I_F = 10\text{mA}, R_L = 280\Omega, d = 0.7\text{mm}$	—	0.2	—	$\mu\text{s}$
Fall Time	$t_f$	$V^+ = 5\text{V}, I_F = 10\text{mA}, R_L = 280\Omega, d = 0.7\text{mm}$	—	0.1	—	$\mu\text{s}$

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## ■ MEASURING SPECIFICATION FOR THRESHOLD INPUT CURRENT



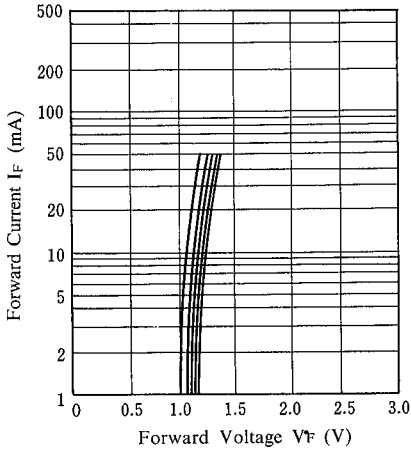
## ■ MAXIMUM RATING CURVES



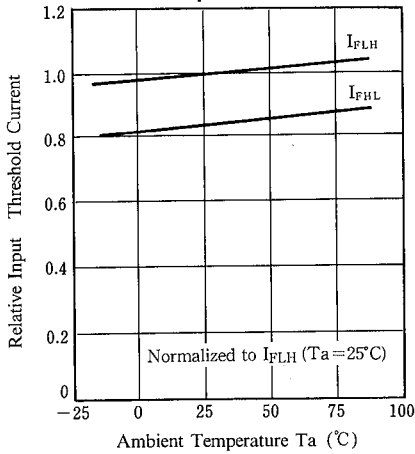
## TYPICAL CHARACTERISTICS

**Forward Current vs. Forward Voltage**

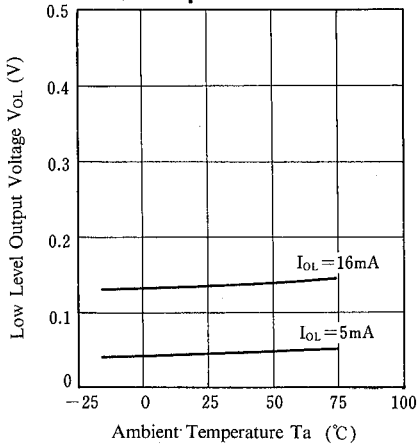
( $T_a=85^\circ\text{C}, 50^\circ\text{C}, 25^\circ\text{C}, 0^\circ\text{C}, -20^\circ\text{C}$ )



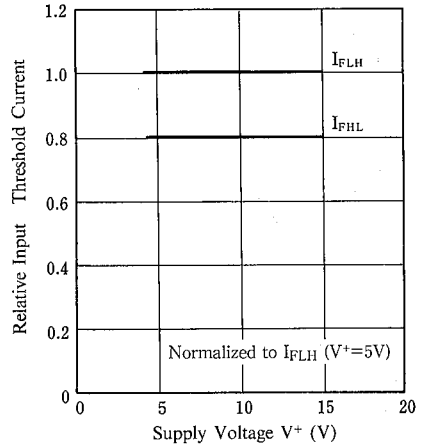
**Input Threshold Current vs. Temperature** ( $V^+=5\text{V}$ )



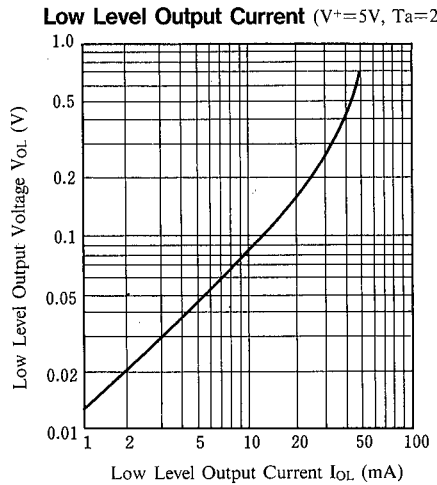
**Low Level Output Voltage vs. Temperature** ( $V^+=5\text{V}$ )



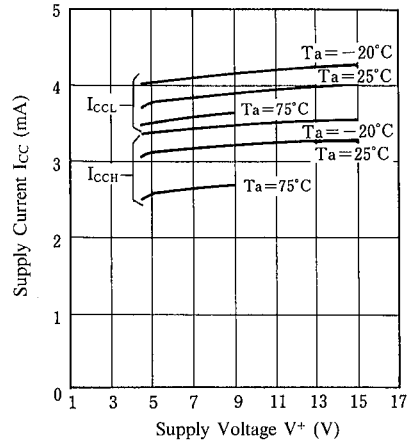
**Input Threshold Current vs. Supply Voltage** ( $T_a=25^\circ\text{C}$ )



**Low Level Output Voltage vs. Low Level Output Current** ( $V^+=5\text{V}, T_a=25^\circ\text{C}$ )

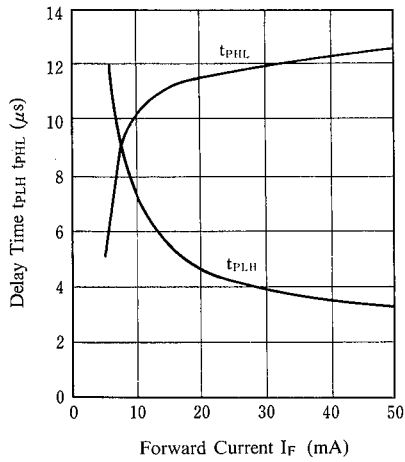


**Supply Current vs. Supply Voltage**



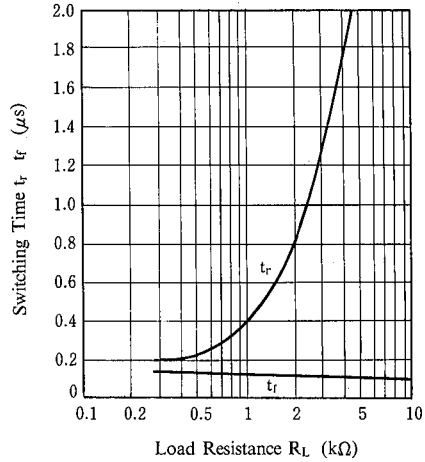
**Delay Time vs. Forward Current**

( $V^+=5V$ ,  $R_L=280\Omega$ ,  $T_a=25^\circ C$ )



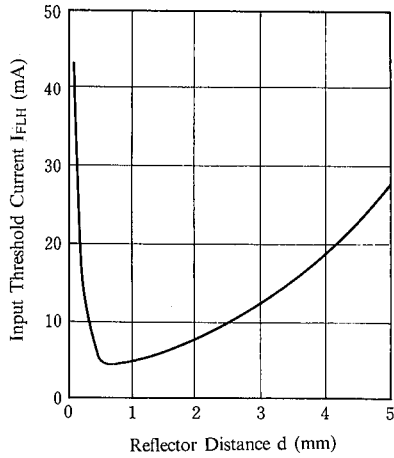
**Switching Time vs. Load Resistance**

( $V^+=5V$ ,  $I_F=10mA$ ,  $T_a=25^\circ C$ )



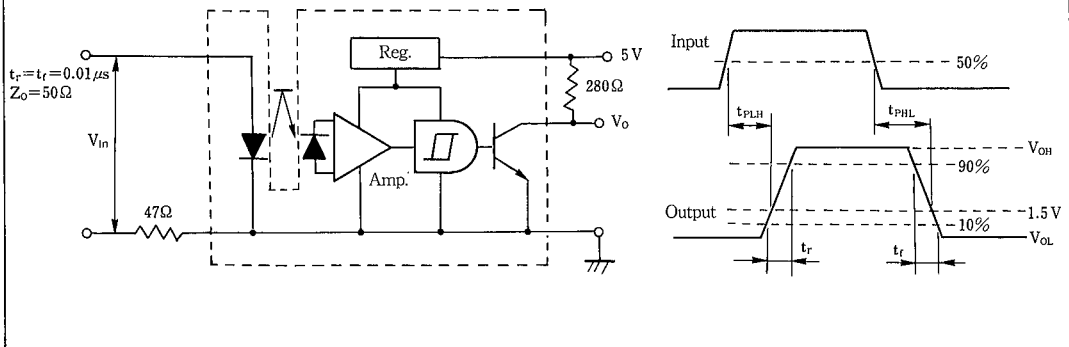
**Input Threshold Current vs. Distance**

( $V^+=5V$ ,  $R_L=280\Omega$ ,  $T_a=25^\circ C$ )



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**Measuring Circuit for Response Time**



## MEMO

**[CAUTION]**

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